

Product data sheet

1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small DFN1010D-3 (SOT1215) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Trench MOSFET technology
- Leadless ultra small and ultra thin SMD plastic package: 1.1 × 1.0 × 0.37 mm
- Exposed drain pad for excellent thermal conduction
- ElectroStatic Discharge (ESD) protection 1.5 kV HBM
- Drain-source on-state resistance R_{DSon} = 59 m Ω
- Very low gate-source threshold voltage for portable applications $V_{GS(th)}$ = -0.68 V

3. Applications

- High-side load switch and charging switch for portable devices
- Power management in battery driven portables
- LED driver
- DC-to-DC converter

4. Quick reference data

| Table 1. Qui | ck reference data | | | | | | |
|------------------------|----------------------------------|---|-----|-----|-----|------|------|
| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
| V _{DS} | drain-source voltage | T _j = 25 °C | | - | - | -12 | V |
| V _{GS} | gate-source voltage | - | | -8 | - | 8 | V |
| I _D | drain current | V _{GS} = -4.5 V; T _{amb} = 25 °C | [1] | - | - | -3.2 | А |
| Static characteristics | | | | | | | |
| R _{DSon} | drain-source on-state resistance | V _{GS} = -4.5 V; I _D = -3.2 A; T _j = 25 °C | | - | 59 | 72 | mΩ |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

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5. Pinning information

| Table 2. | Pinning | information | | |
|----------|---------|-------------|---|--|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| 1 | G | gate | | D |
| 2 | S | source | | |
| 3 | D | drain | 4 3 | G (The second s |
| 4 | D | drain | Transparent top view DFN1010D-3 (SOT1215) | S 017aaa259 |

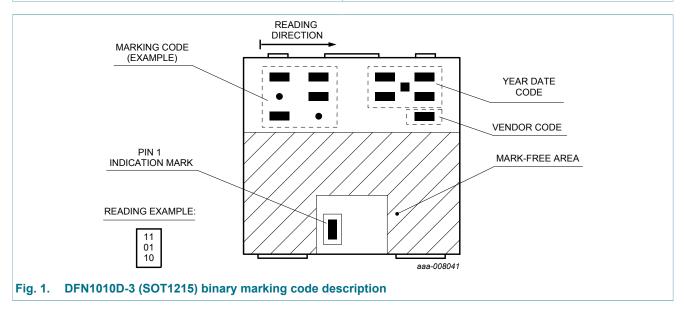
6. Ordering information

| Table 3. Ordering information | | | | | | | |
|-------------------------------|------------|--|---------|--|--|--|--|
| Type number | Package | | | | | | |
| | Name | Description | Version | | | | |
| PMXB65UPE | DFN1010D-3 | DFN1010D-3: plastic thermal enhanced ultra thin small outline package; no leads; 3 terminals; body 1.1 x 1.0 x 0.37 mm | SOT1215 | | | | |

7. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| PMXB65UPE | 01 10 00 |



PMXB65UPE

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8. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | | Min | Мах | Unit | | |
|------------------|-------------------------|---|-----|-----|------|------|--|--|
| V _{DS} | drain-source voltage | T _j = 25 °C | | - | -12 | V | | |
| V _{GS} | gate-source voltage | | | -8 | 8 | V | | |
| I _D | drain current | V_{GS} = -4.5 V; T_{amb} = 25 °C | [1] | - | -3.2 | А | | |
| | | V_{GS} = -4.5 V; T_{amb} = 100 °C | [1] | - | -2.1 | А | | |
| I _{DM} | peak drain current | T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$ | | - | -13 | А | | |
| P _{tot} | total power dissipation | T _{amb} = 25 °C | [2] | - | 317 | mW | | |
| | | | [1] | - | 1070 | mW | | |
| | | T _{sp} = 25 °C | | - | 8330 | mW | | |
| Tj | junction temperature | | | -55 | 150 | °C | | |
| T _{amb} | ambient temperature | | | -55 | 150 | °C | | |
| T _{stg} | storage temperature | | | -65 | 150 | °C | | |
| Source-dra | Source-drain diode | | | | | | | |
| I _S | source current | T _{amb} = 25 °C | [1] | - | -1 | А | | |

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

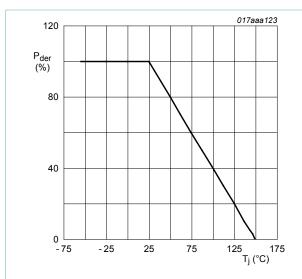


Fig. 2. Normalized total power dissipation as a function of junction temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$

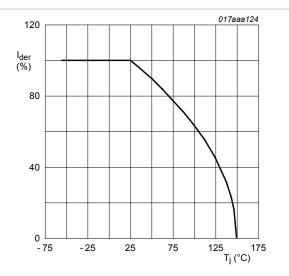
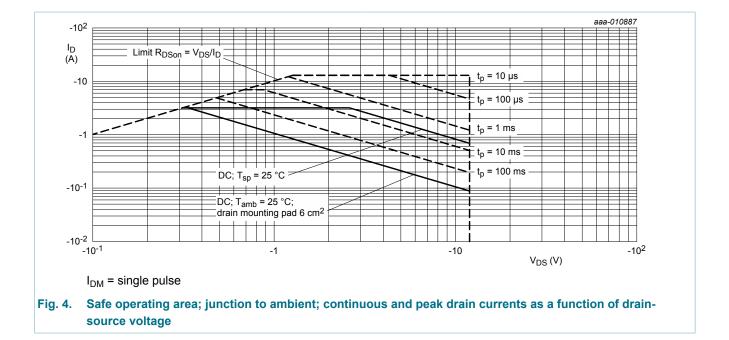


Fig. 3. Normalized continuous drain current as a function of junction temperature

$$I_{der} = \frac{I_D}{I_{D(25^\circ \text{C})}} \times 100 \%$$

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9. Thermal characteristics

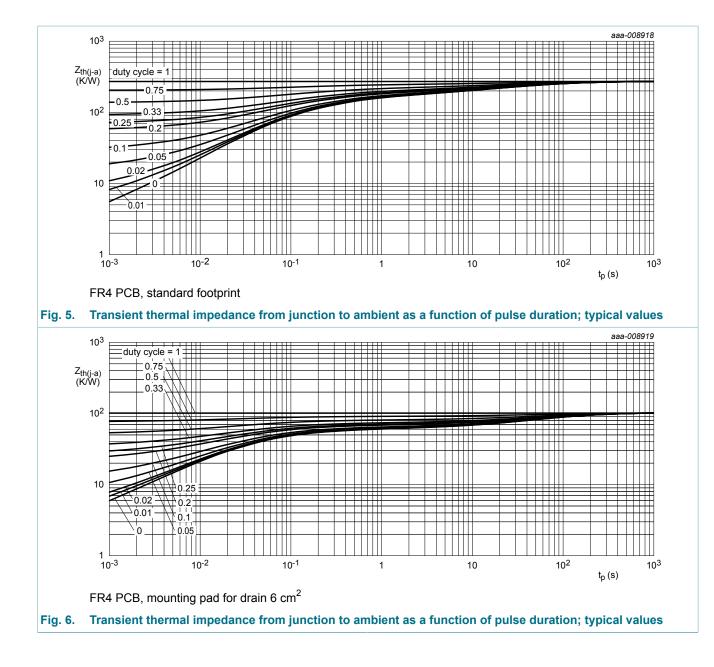
| Table 6. Thermal characteristics | | | | | | | |
|----------------------------------|--|-------------|-----|-----|-----|-----|------|
| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | [1] | - | 271 | 312 | K/W |
| | | | [2] | - | 102 | 117 | K/W |
| R _{th(j-sp)} | thermal resistance from junction to solder point | | | - | 10 | 15 | K/W |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².



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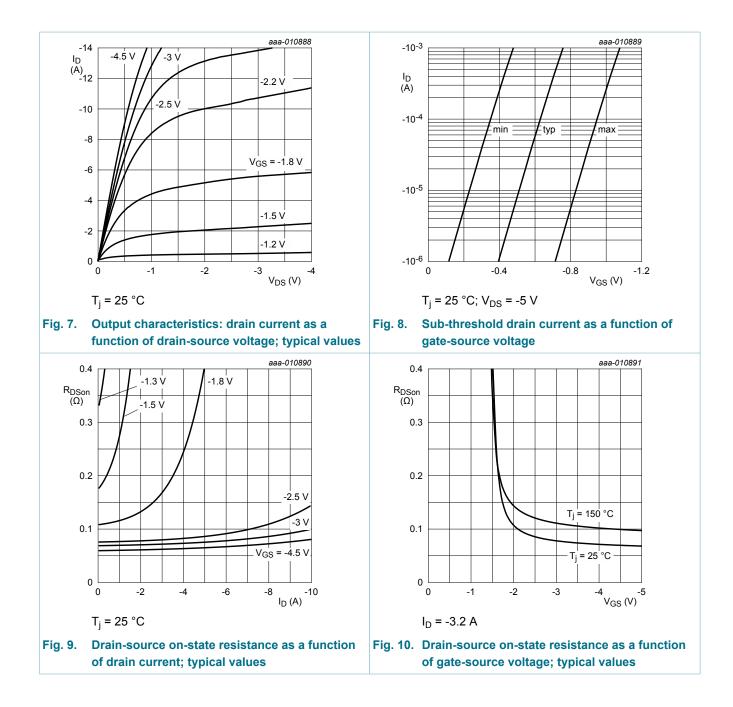
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10. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|-----------------------------------|--|------|-------|------|------|
| Static chara | cteristics | | | | | |
| V _{(BR)DSS} | drain-source breakdown voltage | I_D = -250 µA; V_{GS} = 0 V; T_j = 25 °C | -12 | - | - | V |
| V _{GSth} | gate-source threshold voltage | I_D = -250 µA; V_{DS} = V_{GS} ; T_j = 25 °C | -0.4 | -0.68 | -1 | V |
| I _{DSS} | drain leakage current | V_{DS} = -12 V; V_{GS} = 0 V; T_j = 25 °C | - | - | -1 | μA |
| I _{GSS} | gate leakage current | V_{GS} = -8 V; V_{DS} = 0 V; T_j = 25 °C | - | - | -10 | μA |
| | | V_{GS} = 8 V; V_{DS} = 0 V; T_j = 25 °C | - | - | 10 | μA |
| | | V_{GS} = -4.5 V; V_{DS} = 0 V; T_j = 25 °C | - | - | -1 | μA |
| | | V _{GS} = 4.5 V; V _{DS} = 0 V; T _j = 25 °C | - | - | 1 | μA |
| R _{DSon} | drain-source on-state | V_{GS} = -4.5 V; I _D = -3.2 A; T _j = 25 °C | - | 59 | 72 | mΩ |
| | resistance | V _{GS} = -4.5 V; I _D = -3.2 A; T _j = 150 °C | - | 80 | 98 | mΩ |
| | | V_{GS} = -2.5 V; I _D = -2.7 A; T _j = 25 °C | - | 78 | 98 | mΩ |
| | | V_{GS} = -1.8 V; I _D = -0.4 A; T _j = 25 °C | - | 120 | 200 | mΩ |
| | | V_{GS} = -1.5 V; I _D = -50 mA; T _j = 25 °C | - | 198 | 450 | mΩ |
| | | V_{GS} = -1.2 V; I _D = -10 mA; T _j = 25 °C | - | 880 | - | mΩ |
| 9fs | forward transconductance | V _{DS} = -10 V; I _D = -2 A; T _j = 25 °C | - | 9.4 | - | S |
| R _G | gate resistance | f = 1 MHz | - | 8.7 | - | Ω |
| Dynamic ch | aracteristics | · · · · · | I | | | |
| Q _{G(tot)} | total gate charge | V_{DS} = -6 V; I _D = -3.2 A; V _{GS} = -4.5 V; | - | 6.7 | 12 | nC |
| Q _{GS} | gate-source charge | T _j = 25 °C | - | 1 | - | nC |
| Q _{GD} | gate-drain charge | | - | 1.9 | - | nC |
| C _{iss} | input capacitance | V_{DS} = -6 V; f = 1 MHz; V_{GS} = 0 V; | - | 634 | - | pF |
| C _{oss} | output capacitance | T _j = 25 °C | - | 167 | - | pF |
| C _{rss} | reverse transfer capacitance | | - | 146 | - | pF |
| t _{d(on)} | turn-on delay time | V_{DS} = -6 V; I _D = -3.2 A; V _{GS} = -4.5 V; | - | 6.2 | - | ns |
| r | rise time | R _{G(ext)} = 6 Ω; T _j = 25 °C | - | 22 | - | ns |
| td(off) | turn-off delay time | | - | 27 | - | ns |
| t _f | fall time | | - | 17 | - | ns |
| Source-drai | n diode | | I | | 1 | |
| V _{SD} | source-drain voltage | I _S = -1 A; V _{GS} = 0 V; T _i = 25 °C | - | -0.7 | -1.2 | V |

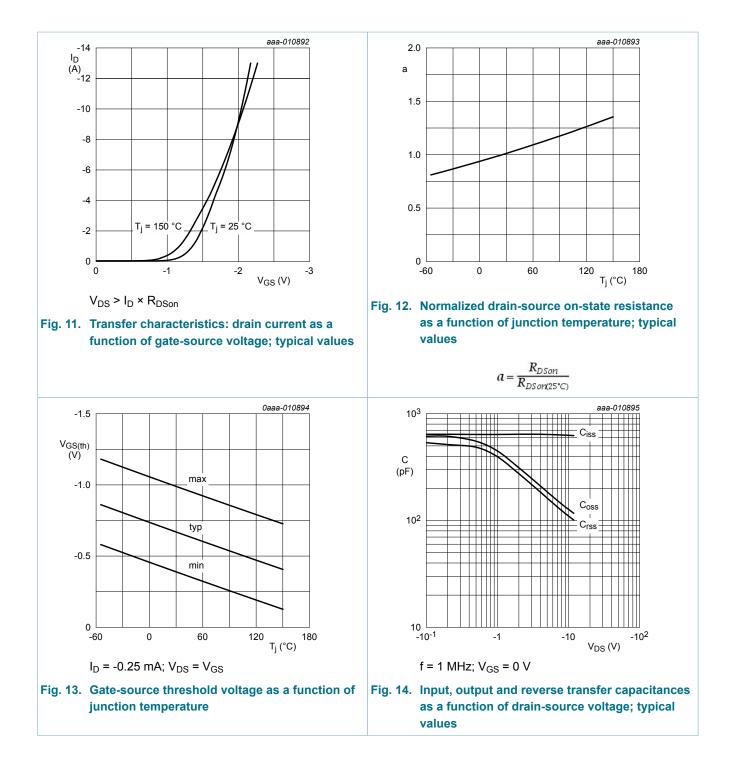
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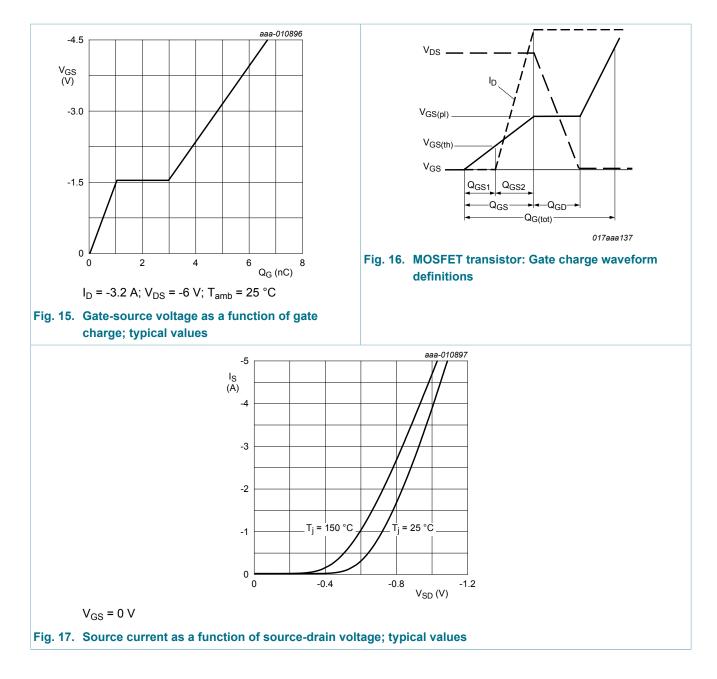


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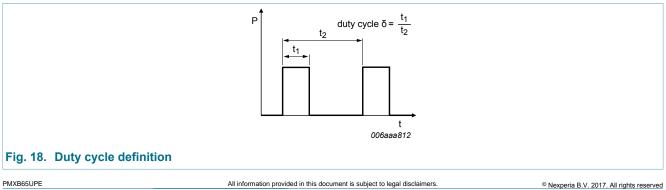
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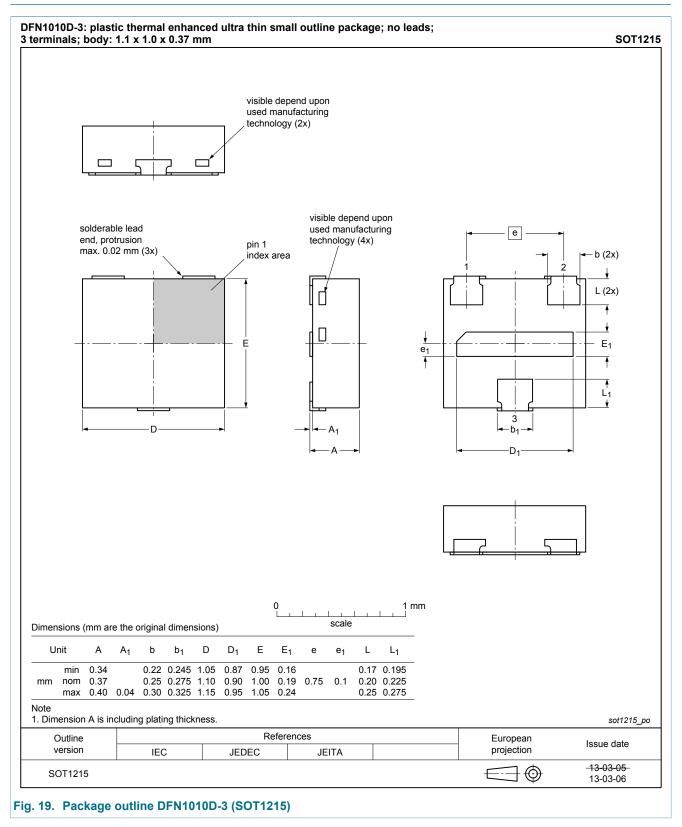


11. Test information



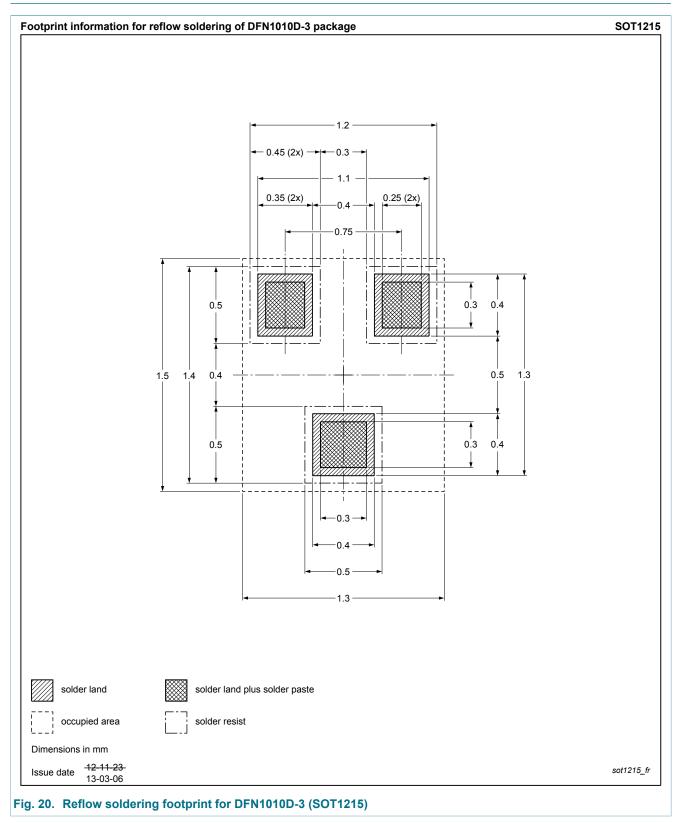
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12. Package outline



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13. Soldering



14. Revision history

| Table 8. Revision his | story | | | |
|-----------------------|---------------------|------------------------|---------------|---------------|
| Data sheet ID | Release date | Data sheet status | Change notice | Supersedes |
| PMXB65UPE v.3 | 20140708 | Product data sheet | - | PMXB65UPE v.2 |
| Modifications: | Product status char | iged | | |
| PMXB65UPE v.2 | 20140218 | Preliminary data sheet | - | PMXB65UPE v.1 |
| PMXB65UPE v.1 | 20140204 | Preliminary data sheet | - | - |

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15. Legal information

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| Document status [1][2] | Product status [3] | Definition |
|--------------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
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